TOSHIBA Multichip Discrete Device

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# HN7G05FU

Power Management Switch Applications, Inverter Circuit Applications, Driver Circuit Applications and Interface Circuit Applications

Q1 (transistor): RN2301 equivalent Q2 (MOSFET): 2SK1830 equivalent

# Q1 (Transistor) Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-10	V
Collector current	IC	-100	mA

# Q2 (MOSFET) Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Drain-source voltage	V <sub>DS</sub>	20	V
Gate-source voltage	V <sub>GSS</sub>	10	V
Drain current	ID	50	mA

# 1. EMITTER 2. BASE 3. DRAIN 4. SOURCE 5. GATE US6 6. COLLECTOR US6 7 DEITA — TOSHIBA 2-2J1E

Weight: 0.0068 g (typ.)

## Marking

# Q1, Q2 Common Ratings (Ta = 25°C)

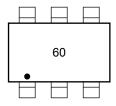
Characteristic	Symbol	Rating	Unit
Power dissipation	P (Note 1)	200	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

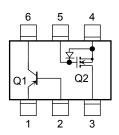
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate,

etc).

Note 1: Total rating



### **Equivalent Circuit (top view)**



# Q1 (Transistor) Electrical Characteristics (Ta = 25°C)

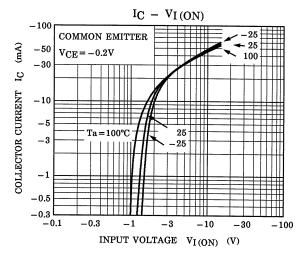
ww.DataSheet4U.com Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cutoff current	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-100	nA
Collector Cuton Current	I <sub>CEO</sub>	$V_{CE} = -50 \text{ V}, I_{E} = 0$	_	_	-500	nA
Emitter cutoff current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_C = 0$	-0.82	_	-1.52	mA
DC current gain	h <sub>FE</sub>	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	30	_	_	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	$I_C = -5 \text{ mA}, I_B = -0.25 \text{ mA}$	_	-0.1	-0.3	V
Input voltage (ON)	V <sub>I(ON)</sub>	$V_{CE} = -0.2 \text{ V}, I_{C} = -5 \text{ mA}$	-1.1	_	-2.0	V
Input voltage (OFF)	V <sub>I(OFF)</sub>	$V_{CE} = -5 \text{ V}, I_{C} = -0.1 \text{ mA}$	-1.0	_	-1.5	V
Input resistor	R1	_	3.29	4.7	6.11	kΩ
Resistor ratio	R1/R2	_	0.9	1.0	1.1	

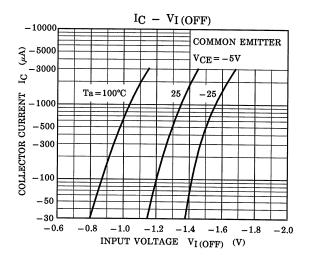
# Q2 (MOSFET) Electrical Characteristics (Ta = 25°C)

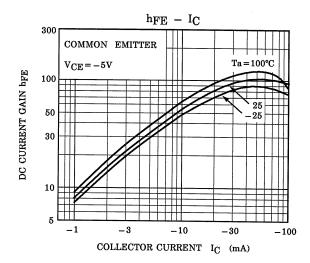
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 0	_	_	1	μА
Drain-source breakdown voltage	V (BR) DSS	$I_D = 100 \mu A, V_{GS} = 0$	20	_	_	V
Drain cutoff current	I <sub>DSS</sub>	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0	_	_	1	μА
Gate threshold voltage	$V_{th}$	$V_{DS} = 3 \text{ V}, I_D = 0.1 \text{ mA}$	0.5	_	1.5	V
Forward transfer admittance	Y <sub>fs</sub>	$V_{DS} = 3 \text{ V}, I_D = 10 \text{ mA}$	20	_	_	mS
Drain-source ON-resistance	R <sub>DS (ON)</sub>	$I_D$ = 10 mA $V_{GS}$ = 2.5 $V$	_	20	40	Ω

# Q1 (Transistor)

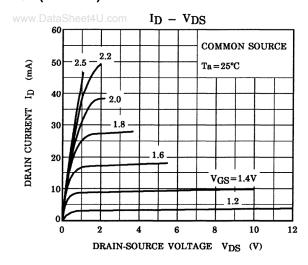
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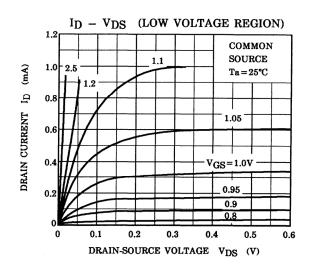


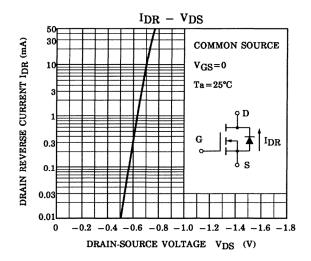


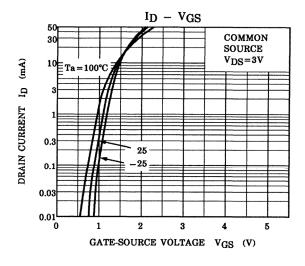


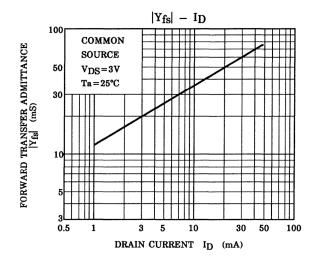
# Q2 (S-MOS)

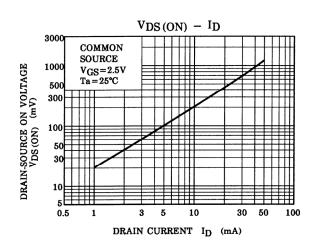






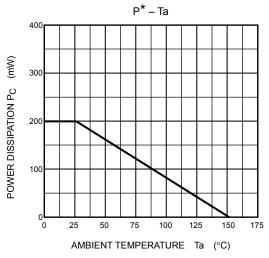






# Q1, Q2 common

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\*:Total rating

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